

Vishay Semiconductors

Silicon Rectifier Diodes, (Stud Version) 15 A



DO-5 (DO-203AB)

FEATURES

- · Low thermal impedance
- High case temperature



- · Excellent reliability
- · Maximum design flexibility
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

PRIMARY CHARACTERISTICS		
I _{F(AV)}	15 A	
Package	DO-5 (DO-203AB)	
Circuit configuration	Single	

PARAMETER	TEST CONDITIONS	VALUES	UNITS	
TANAMETEN	TEST SONDITIONS			
I _{F(AV)}		15 ⁽¹⁾	Α	
'F(AV)	T _C	150 ⁽¹⁾	°C	
I _{FSM}	50 Hz	239	Α	
	60 Hz	250 ⁽¹⁾		
I ² t	50 Hz	286	A ² s	
	60 Hz	260		
$I^2\sqrt{t}$		3870	A ² √s	
V _{RRM}	Range	50 to 600	V	
T _J		-65 to +175	°C	

Note

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS			
TYPE NUMBER	V_{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE ($T_J = -65~^{\circ}\text{C}$ TO 175 $^{\circ}\text{C}$)	V_{RM} , MAXIMUM DIRECT REVERSE VOLTAGE (T _J = -65 °C TO 175 °C)	
VS-1N3208	50 ⁽¹⁾	50 ⁽¹⁾	
VS-1N3209	100 (1)	100 ⁽¹⁾	
VS-1N3210	200 ⁽¹⁾	200 ⁽¹⁾	
VS-1N3211	300 (1)	300 (1)	
VS-1N3212	400 (1)	400 (1)	
VS-1N3213	500 ⁽¹⁾	500 ⁽¹⁾	
VS-1N3214	600 (1)	600 ⁽¹⁾	

- Basic type number indicates cathode to case. For anode to case, add "R" to part number, e.g. 1N3208R, 1N3209R
- (1) JEDEC® registered values

⁽¹⁾ JEDEC® registered values



Vishay Semiconductors

FORWARD CONDUCTION					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current	l=	180° sinusoidal conduction		15 ⁽¹⁾	Α
at case temperature	I _{F(AV)}			150 ⁽¹⁾	°C
		Half cycle 50 Hz sine wave	Following any rated load condition and with rated	239	А
		or 6 ms rectangular pulse			
		Half cycle 60 Hz sine wave	V _{RRM} applied	250 ⁽¹⁾	
Maximum peak one cycle	I _{FSM}	or 5 ms rectangular pulse			
non-repetitive surge current		Half cycle 50 Hz sine wave	Fallerian and material land	284	
		or 6 ms rectangular pulse	Following any rated load condition and with V _{RRM}		
		Half cycle 60 Hz sine wave	applied following surge = 0	297	
		or 5 ms rectangular pulse			
Maximum I ² t for fusing	_ I ² t	t = 10 ms	With rated V_{RRM} applied following surge, initial $T_J = 150 ^{\circ}\text{C}$	286	A ² s
		t = 8.3 ms		260	
Maximum I ² t for individual device fusing		t = 10 ms	With $V_{RRM} = 0$ following surge, initial $T_J = 150 ^{\circ}\text{C}$	403	
		t = 8.3 ms		368	
Maximum l ² √t for individual device fusing	I ² √t ⁽²⁾	t = 0.1 ms to 10 ms, V _{RRM} = 0 following surge		3870	A ² √s
Maximum forward voltage drop	V_{FM}	I _{F(AV)} = 15 A (47.1 A peak), T _C = 150 °C 1.5		1.5 ⁽¹⁾	V
Maximum average reverse current	I _{R(AV)}	Maximum rated I _{F(AV)} and T _C = 150 °C		10 ⁽¹⁾	mA

Notes

(1) JEDEC® registered values

(2) I^2t for time $t_x = I^2\sqrt{t} \times \sqrt{t_x}$

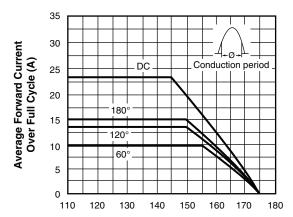
THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction operating and storage temperature range	T _J , T _{Stg}		-65 to 175 ⁽¹⁾	°C	
Maximum internal thermal resistance, junction to case	R _{thJC}	DC operation	0.65	°C/W	
Thermal resistance, case to sink	R _{thCS}	Mounting surface, smooth, flat and greased	0.25		
		Not lubricated thread, tighting on nut (2)	3.4	(30)	
Maximum allowable mounting		Lubricated thread, tighting on nut (2)		2.3 (20)	
torque (+0 %, -10 %)		Not lubricated thread, tighting on hexagon (3)	4.2	(37)	
		Lubricated thread, tighting on hexagon (3)	3.2	(28)	
Waight			28.5	g	
Weight			1	oz.	
Case style		JEDEC® DO-5 (DO-203))-203AB)	

Notes

- (1) JEDEC® registered values
- (2) Recommended for pass-through holes
- (3) Recommended for holed threaded heatsinks

www.vishay.com

Vishay Semiconductors



Maximum Allowable Case Temperature (°C)

Fig. 1 - Average Forward Current vs. Maximum Allowable Case Temperature

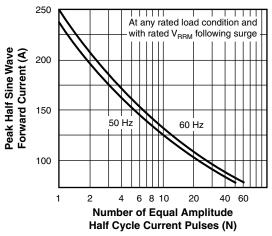
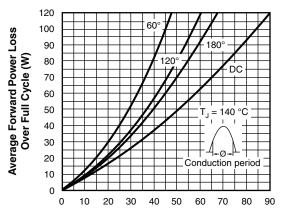
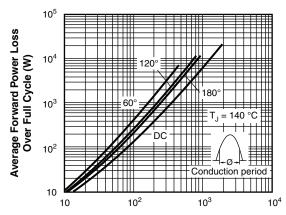


Fig. 2 - Maximum Non-Repetitive Surge Current vs. Number of Current Pulses



Average Forward Current Over Full Cycle (A)

Fig. 3 - Maximum Low Level Forward Power Loss vs. Average Forward Current



Average Forward Current Over Full Cycle (A)

Fig. 4 - Maximum High Level Forward Power Loss vs. Average Forward Current

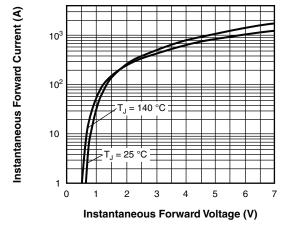


Fig. 5 - Maximum Forward Voltage vs. Forward Current

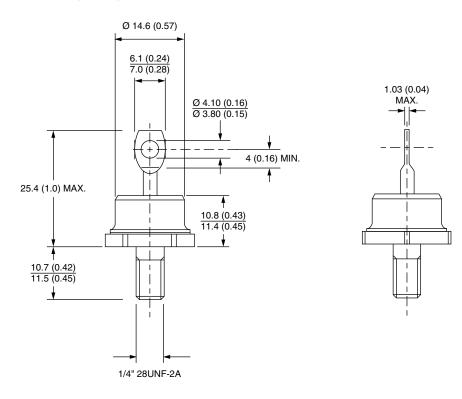
LINKS TO RELATED DOCUMENTS		
Dimensions	www.vishay.com/doc?95360	

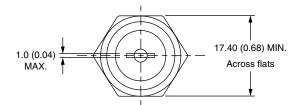


Vishay Semiconductors

DO-203AB (DO-5) for 1N1183, 1N3765, 1N1183A, 1N2128A, 1N3208 Series

DIMENSIONS in millimeters (inches)







Legal Disclaimer Notice

Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Vishay products are not designed for use in life-saving or life-sustaining applications or any application in which the failure of the Vishay product could result in personal injury or death unless specifically qualified in writing by Vishay. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.